NSN 5961-01-323-4919

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-323-4919 **Inclosure Material:** Plastic **Overall Length:** 0.190 inches **Terminal Length:** 0.500 inches **Overall Height:** 0.190 inches **Overall Width:** 0.145 inches **Function For Which Designed: Amplifier Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-226aa **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 625.0 milliwatts small-signal input power, common-collector absolute **Transfer Ratio:** 20000.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No